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SN74GTL16622A 18-BIT LVTTL-TO-GTL/GTL+ BUS TRANSCEIVER

SCBS673F-AUGUST 1996-REVISED APRIL 2005

FEATURES

- Member of Texas Instruments Widebus™ Family
- OEC[™] Circuitry Improves Signal Integrity and Reduces Electromagnetic Interference
- D-Type Flip-Flops With Qualified Storage Enable
- Translates Between GTL/GTL+ Signal Levels
 and LVTTL Logic Levels
- Supports Mixed-Mode (3.3 V and 5 V) Signal Operation on A-Port and Control Inputs
- I_{off} Supports Partial-Power-Down Mode
 Operation
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors on A Port
- Distributed V_{CC} and GND Pins Minimize High-Speed Noise
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

The SN74GTL16622A is an 18-bit registered bus transceiver that provides LVTTL-to-GTL/GTL+ and GTL/GTL+-to-LVTTL signal-level translation. This device is partitioned as two separate 9-bit transceivers with individual clock-enable controls and contains D-type flip-flops for temporary storage of data flowing in either direction. This device provides an interface between cards operating at LVTTL logic levels and a backplane operating at GTL/GTL+ signal levels. Higher-speed operation is a direct result of the reduced output swing (<1 V), reduced input threshold levels, and OEC[™] circuitry.

D	GG PAC (TOP VI		
OEAB [$[] \bigcirc$	64	CLKAB
1A1	2	63	1CEAB
GND [3	62	1CEBA
1A2		61	1B1
1A3 [1	60	GND
GND [59	1B2
V _{CC}	7	58	1B3
1A4 [8	57	V _{cc}
GND	9	56	1B4
1A5 [1	55	1B5
1A6 [11	54	1B6
GND	12	53	GND
1A7	13	52	1B7
1A8	14	51	1B8
GND [15	50	GND
1A9 [16	49	1B9
2A1 [17	48	2B1
GND [18	47	GND
2A2 [19	46	2B2
2A3 [20	45	2B3
GND [21	44	GND
2A4 [22	43	2B4
2A5 [23	42	2B5
GND [24	41] 2B6
2A6	25	40	V _{REF}
V _{CC}	26	39	2B7
GND [27	38] 2B8
2A7 [28	37] GND
2A8	29	36] 2B9
GND [30	35	2CEBA
2A9 [31	34	2 2 CEAB
	32	33	1 CLKBA

The user has the flexibility of using this device at either GTL ($V_{TT} = 1.2$ V and $V_{REF} = 0.8$ V) or the preferred higher noise margin GTL+ ($V_{TT} = 1.5$ V and $V_{REF} = 1$ V) signal levels. GTL+ is the Texas Instruments derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The B port normally operates at GTL or GTL+ signal levels, while the A-port and control inputs are compatible with LVTTL logic levels and are 5-V tolerant. V_{REF} is the reference input voltage for the B port.

Data flow in each direction is controlled by the output-enable (OEAB and OEBA) and clock (CLKAB and CLKBA) inputs. The clock-enable (CEAB and CEBA) inputs control each 9-bit transceiver independently, which makes the device more versatile.

PDPlease be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

For A-to-B data flow, the device operates on the low-to-high transition of CLKAB if CEAB is low. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state. Data flow for B to A is similar to that of A to B, but uses OEBA, CLKBA, and CEBA.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Active bus-hold circuitry holds unused or undriven LVTTL inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
–40°C to 85°C	TSSOP – DGG	Tape and reel	SN74GTL16622ADGGR	GTL16622A	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE⁽¹⁾

	INP	JTS		OUTPUT	MODE
CEAB	OEAB	CLKAB	Α	В	MODE
Х	Н	Х	Х	Z	Isolation
Н	L	Х	Х	B ₀ ⁽²⁾	Latabad storage of A data
Х	L	H or L	Х	B ₀ ⁽²⁾ B ₀ ⁽²⁾	Latched storage of A data
L	L	\uparrow	L	L	Clocked storage of A data
L	L	\uparrow	н	н	Clocked storage of A data

(1) A-to-B data flow is shown. B-to-A data flow is similar, but uses OEBA, CLKBA, and CEBA.

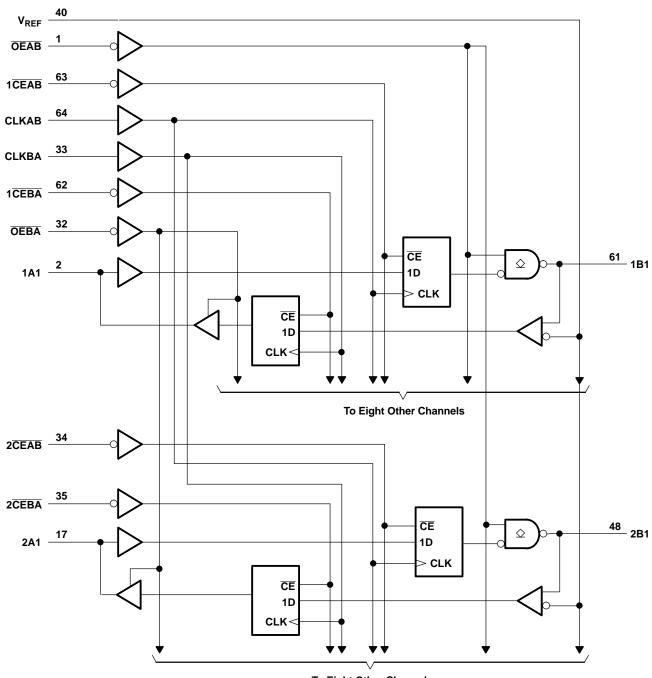
(2) Output level before the indicated steady-state input conditions are established



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LOGIC DIAGRAM (POSITIVE LOGIC)

To Eight Other Channels

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range				V
V _I Input vol	Input voltage range ⁽²⁾	A-port and control inputs	-0.5	6.5	V
		B port and V _{REF}	-0.5	4.6	v
V	Voltage range applied to any output in the high or power-off state ⁽²⁾	A port	-0.5	6.5	V
V _O Vol		B port	-0.5	4.6	v
	Current into any output in the low state	A port		48	٣A
I _O	Current into any output in the low state	B port		100	mA
I _O	Current into any A-port output in the high state ⁽³⁾			48	mA
	Continuous current through each V _{CC} or GND			±100	mA
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current V _O < 0				mA
θ_{JA}	Package thermal impedance ⁽⁴⁾				°C/W
T _{stg}	Storage temperature range				°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings (1) only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. The current flows only when the output is in the high state and $V_O > V_{CC}$. The package thermal impedance is calculated in accordance with JESD 51-7. (2)

(3)

(4)

Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		3.15	3.3	3.45	V
V	Termination voltage	GTL	1.14	1.2	1.26	V
V _{TT}	Termination voltage	GTL+	1.35	1.5	1.65	v
V		GTL	0.74	0.8	0.87	V
V_{REF}	V _{REF} Reference voltage	GTL+	0.87	1	1.1	v
V _I Input voltage	B port			V _{TT}	V	
	Except B port			5.5	v	
V		B port	V _{REF} + 50 mV			
V _{IH}	High-level input voltage	Except B port				V
		B port			V _{REF} – 50 mV	V
V _{IL}	Low-level input voltage	Except B port			0.8	v
I _{IK}	Input clamp current				–18	mA
I _{OH}	High-level output current	A port			-24	mA
I _{OL} Low-lev	I and a stand and a stand	A port			24	
	Low-level output current	B port			50	mA
T _A	Operating free-air temperature		-40		85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

(2)

Normal connection sequence is GND first and $V_{CC} = 3.3 \text{ V}$, I/O, control inputs, V_{TT} and V_{REF} (any order) last. V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances if the dc recommended I_{OL} ratings are not exceeded. (3)

(4) V_{REF} can be adjusted to optimize noise margins, but normally is two-thirds V_{TT}.





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Electrical Characteristics

over recommended operating free-air temperature range for GTL/GTL+ (unless otherwise noted)

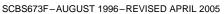
PARAMETER		TEST	TEST CONDITIONS			UNIT	
V _{IK}		V _{CC} = 3.15 V,	I _I = -18 mA		-1.2	V	
		$V_{CC} = 3.15 \text{ V} \text{ to } 3.45 \text{ V},$	I _{OH} = −100 μA	V _{CC} – 0.2			
V _{OH}	A port	N/ 0.45 V/	I _{OH} = -12 mA	2.4		V	
		V _{CC} = 3.15 V	$I_{OH} = -24 \text{ mA}$	2			
		V_{CC} = 3.15 V to 3.45 V,	I _{OL} = 100 μA		0.2		
	A port	V 245 V	I _{OL} = 12 mA		0.4		
		V _{CC} = 3.15 V	I _{OL} = 24 mA		0.5		
V _{OL}		V _{CC} = 3.15 V to 3.45 V,	I _{OL} = 100 μA		0.2	V	
	D. nort		I _{OL} = 10 mA		0.2		
	B port	V _{CC} = 3.15 V	I _{OL} = 40 mA		0.4		
					0.55		
I ₁ B port A-port and control inputs	B port	V _{CC} = 3.45 V,	$V_{I} = V_{TT}$ or GND		±5		
	A-port and control inputs	N/ 0.45 V/	$V_{I} = V_{CC}$ or GND		±5	±5 μΑ	
		V _{CC} = 3.45 V	$V_{I} = 5.5 V \text{ or GND}$		±20		
I _{off}	L	V _{CC} = 0,	V_{I} or V_{O} = 0 to 5.5 V		100	μΑ	
	A port $V_{CC} = 3.15 V$		V _I = 0.8 V	75			
I _{I(hold)}			V ₁ = 2 V	-75		μA	
		$V_{CC} = 3.45 V^{(2)},$	$V_{I} = 0.8 V \text{ to } 2 V$		±500		
I _{OZ} ⁽³⁾	A port	V _{CC} = 3.45 V,	$V_{O} = V_{CC}$ or GND		±10	μΑ	
I _{OZH}	B port	V _{CC} = 3.45 V,	V _O = 1.5 V		10	μA	
		V _{CC} = 3.45 V,	Outputs high		60		
I _{CC}	A or B port	$I_{O} = 0,$	Outputs low		60	mA	
		$V_{I} = V_{CC}$ or GND	Outputs disabled		60		
$\Delta I_{CC}^{(4)}$		V_{CC} = 3.45 V, A-port or cor One input at V_{CC} – 0.6 V	trol inputs at V_{CC} or GND,		500	μA	
Ci	Control inputs	V _I = 3.15 V or 0		2	2.5 3	pF	
C	A port	$V_{\rm c} = 2.15 V_{\rm c} cr 0$			6 8	рF	
C _{io}	B port	— V _O = 3.15 V or 0		(6.5 8.5	ρг	

(1)

All typical values are at V_{CC} = 3.3 V, T_A = 25°C. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to (2) another.

(3)

For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. (4)





Timing Requirements

over recommended ranges of supply voltage and operating free-air temperature for GTL (unless otherwise noted)

			MIN	MAX	UNIT
f _{clock}	Clock frequency			200	MHz
t _w	Pulse duration, CLK high or low		2.5		ns
		Data before CLK↑	2.1		
t _{su}	Setup time	CE before CLK↑	3.3		ns
t _h Ho		Data after CLK↑	0.3		
	Hold time CE after CLK↑				ns

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature for GTL (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP ⁽¹⁾ MAX	UNIT
f _{max}			200		MHz
t _{PLH}	CLKAB	В	2.5	5.5	20
t _{PHL}	CERAB	D	2.2	5.5	ns
t _{dis}	OEAB	В	1.7	4.8	20
t _{en}	UEAD	D	2.2	5.2	ns
Slew rate	Both transition		0.5	V/ns	
t _r	Transition time, B ou	utputs (0.6 V to 1 V)	0.6	2.2	ns
t _f	Transition time, B ou	utputs (1 V to 0.6 V)	0.4	1.5	ns
t _{PLH}	CLKBA	А	2.1	5.3	
t _{PHL}	CERBA	A	2.1	5	ns
t _{en}		۸	1.7	5	20
t _{dis}	OEBA	A	2.3	5.5	ns

(1) All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



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Timing Requirements

over recommended ranges of supply voltage and operating free-air temperature for GTL+ (unless otherwise noted)

			MIN	MAX	UNIT
f _{clock}	Clock frequency			200	MHz
t _w	Pulse duration, CLK high or low		2.5		ns
		Data before CLK1	2.4		
t _{su}	Setup time	CE before CLK↑	3.2		ns
	Light time	Data after CLK↑	0.2		
τ _h	Hold time	0		ns	

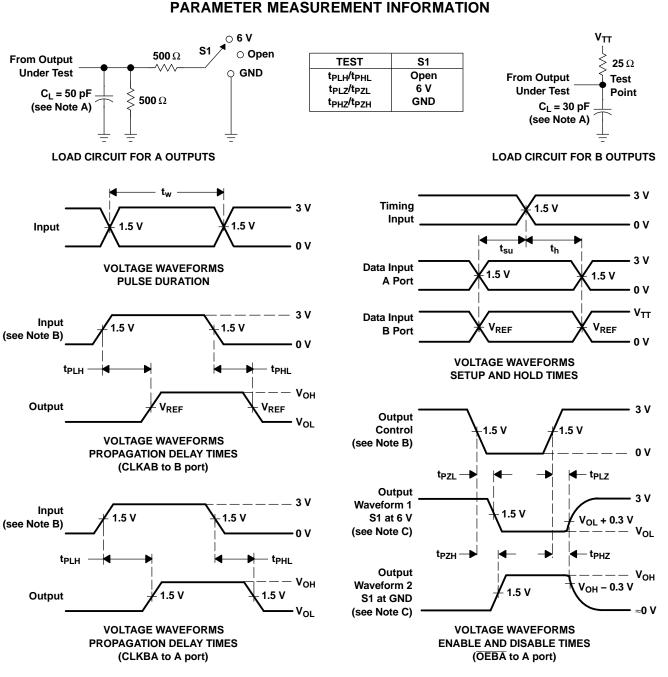
Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature for GTL+ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP ⁽¹⁾	МАХ	UNIT
f _{max}			200			MHz
t _{PLH}	CLKAB	В	2.6	4	5.6	20
t _{PHL}	CERAB	D	2.3	4	5.7	ns
t _{PLH}	OEAB	В	2.4	3.8	5.2	20
t _{PHL}	OEAB	D	1.8	3.4	5	ns
Slew rate	Both transition	ons (B port)		0.5		V/ns
t _r	Transition time, B out	puts (0.6 V to 1.3 V)	1	1.6	2.7	ns
t _f	Transition time, B out	puts (1.3 V to 0.6 V)	0.5	1.1	3.2	ns
t _{PLH}	CLKBA	А	2	3.8	5.3	ns
t _{PHL}	CERBA	~	1.9	3.6	5	115
t _{en}	OEBA	А	1.9	3.6	5	20
t _{dis}	ОЕВА	A	2.1	4	5.5	ns

(1) All typical values are at $V_{CC} = 3.3$ V, $T_A = 25^{\circ}C$.

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NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- C. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

5-Sep-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74GTL16622ADGGRE4	ACTIVE	TSSOP	DGG	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74GTL16622ADGGR	ACTIVE	TSSOP	DGG	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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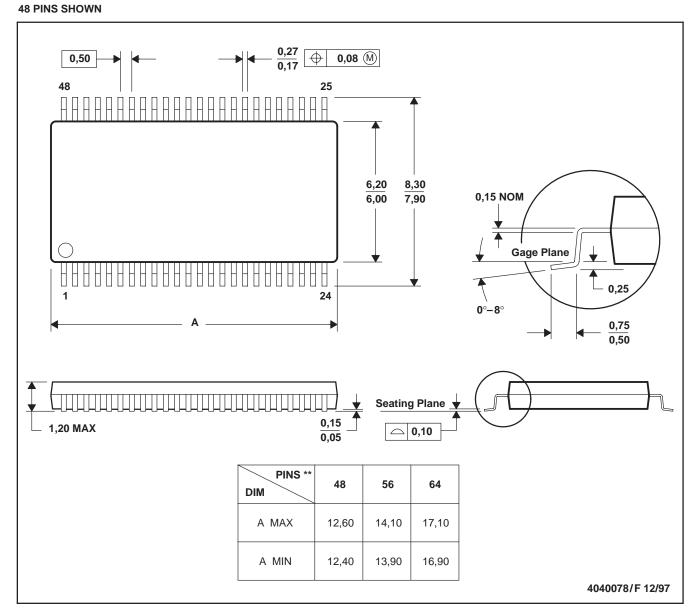
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MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G**)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



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